

# **SPI Serial Persistent SRAM Memory**

(AS3001401, AS3004401, AS3008401, AS3016401)

### **Features**

- Interface
  - Serial Peripheral Interface SPI, up to 50MHz clock rate
- Technology
  - 40nm pMTJ STT-MRAM
    - Virtually unlimited Data Endurance and Data Retention (see *Endurance & Retention* on page 20)
- Density
  - 1Mb, 4Mb, 8Mb, 16Mb
- Operating Voltage Range
  - Vcc: 2.70V 3.60V
- Operating Temperature Range
  - Industrial: -40°C to 85°C
  - Industrial Plus: -40°C to 105°C

- Packages
  - 8-pad WSON (5.0mm x 6.0mm)
  - 8-pin SOIC (5.2mm x 5.2mm)
- Data Protection
  - Hardware Based
    - Write Protect Pin (WP#)
  - Software Based
    - Address Range Selectable through Configuration bits (Top/Bottom, Block Protect [2:0])
- Supports JEDEC Reset
- RoHS & REACH Compliant

### **Performance**

Revision: B

| Device Operation                       | Typical Values | Units |
|--|----------------|-------|
| Frequency of Operation                 | 50 (maximum)   | MHz   |
| Standby Current                        | 160 (typical)  | μA    |
| Deep Power Down Current                | 5 (typical)    | μA    |
| Active Read Current - (1-1-1) @ 50MHz  | 8 (typical)    | mA    |
| Active Write Current - (1-1-1) @ 50MHz | 14 (typical)   | mA    |



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| Limited Warranty  | Error! Bookmark not defined. |
| Revision History  | 31                           |



## **General Description**

ASxxxx401 is a magneto-resistive random-access memory (MRAM). It is offered in density ranging from 1Mbit to 16Mbit. MRAM technology is analogous to Flash technology with SRAM compatible read/write timings (Persistent SRAM, P-SRAM). Data is always non-volatile.

Figure 1: Technology Comparison

|                   | SRAM | Flash | EEPROM | MRAM     |
|-------------------|------|-------|--------|----------|
| Non-Volatility    | _    | V     | √      | √        |
| Write Performance | V    | _     | _      | <b>√</b> |
| Read Performance  | V    | _     | _      | √        |
| Endurance         | V    | _     | _      | V        |
| Power             | _    | _     | _      | <b>√</b> |

MRAM is a true random-access memory; allowing both reads and writes to occur randomly in memory. MRAM is ideal for applications that must store and retrieve data without incurring large latency penalties. It offers low latency, low power, infinite endurance and scalable non-volatile memory technology.

ASxxxx401 has a Serial Peripheral Interface (SPI). SPI is a synchronous interface which uses separate lines for data and clock to help keep the host and slave in perfect synchronization. The clock tells the receiver exactly when to sample the bits on the data line. This can be either the rising (low to high) or falling (high to low) or both edges of the clock signal; please consult the instruction sequences in this datasheet for more details. When the receiver detects that correct edge, it can latch in the data.

ASxxxx401 is available in small footprint 8-pad WSON and 8-pin SOIC packages. These packages are compatible with similar low-power volatile and non-volatile products.

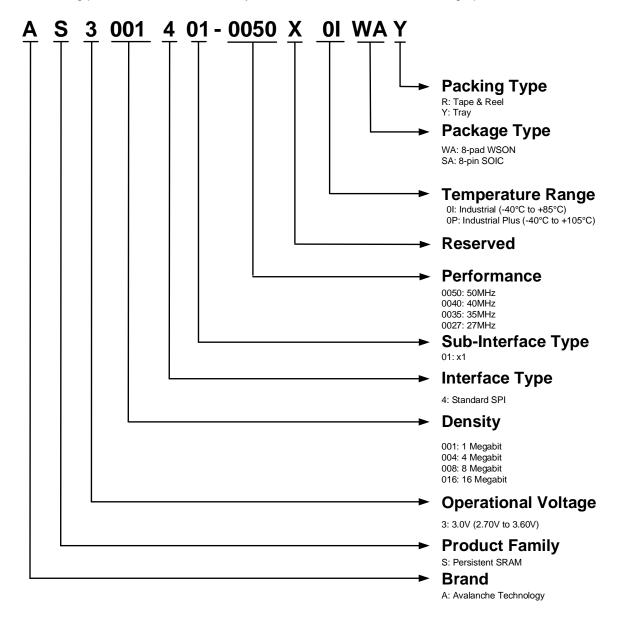
ASxxxx401 is offered with industrial (-40°C to 85°C) and industrial plus (-40°C to 105°C) operating temperature ranges.



## **Ordering Options**

Revision: B

The ordering part numbers are formed by a valid combination of the following options:





### Valid Combinations — Standard

Valid Combinations list includes device configurations currently available. Contact your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Table 1: Valid Combinations List

|                     |                      | Valid Combinations - 50MH | z               |                      |
|---------------------|----------------------|---------------------------|-----------------|----------------------|
| Base<br>Part Number | Temperature<br>Range | Package<br>Type           | Packing<br>Type | Part<br>Number       |
| AS3001401-0050X     | 0I, 0P               | WA, SA                    | R, Y            | AS3001401-0050X0IWAR |
|                     |                      |                           |                 | AS3001401-0050X0IWAY |
|                     |                      |                           |                 | AS3001401-0050X0ISAR |
|                     |                      |                           |                 | AS3001401-0050X0ISAY |
|                     |                      |                           |                 | AS3001401-0050X0PWAR |
|                     |                      |                           |                 | AS3001401-0050X0PWAY |
|                     |                      |                           |                 | AS3001401-0050X0PSAR |
|                     |                      |                           |                 | AS3001401-0050X0PSAY |
| AS3004401-0050X     | 0I, 0P               | WA, SA                    | R, Y            | AS3004401-0050X0IWAR |
|                     |                      |                           |                 | AS3004401-0050X0IWAY |
|                     |                      |                           |                 | AS3004401-0050X0ISAR |
|                     |                      |                           |                 | AS3004401-0050X0ISAY |
|                     |                      |                           |                 | AS3004401-0050X0PWAR |
|                     |                      |                           |                 | AS3004401-0050X0PWAY |
|                     |                      |                           |                 | AS3004401-0050X0PSAR |
|                     |                      |                           |                 | AS3004401-0050X0PSAY |
| AS3008401-0050X     | 0I, 0P               | WA, SA                    | R, Y            | AS3008401-0050X0IWAR |
|                     |                      |                           |                 | AS3008401-0050X0IWAY |
|                     |                      |                           |                 | AS3008401-0050X0ISAR |
|                     |                      |                           |                 | AS3008401-0050X0ISAY |
|                     |                      |                           |                 | AS3008401-0050X0PWAR |
|                     |                      |                           |                 | AS3008401-0050X0PWAY |
|                     |                      |                           |                 | AS3008401-0050X0PSAR |
|                     |                      |                           |                 | AS3008401-0050X0PSAY |
| AS3016401-0050X     | 0I, 0P               | WA, SA                    | R, Y            | AS3016401-0050X0IWAR |
|                     |                      |                           |                 | AS3016401-0050X0IWAY |
|                     |                      |                           |                 | AS3016401-0050X0ISAR |
|                     |                      |                           |                 | AS3016401-0050X0ISAY |
|                     |                      |                           |                 | AS3016401-0050X0PWAR |
|                     |                      |                           |                 | AS3016401-0050X0PWAY |
|                     |                      |                           |                 | AS3016401-0050X0PSAR |
|                     |                      |                           |                 | AS3016401-0050X0PSAY |
|                     |                      |                           |                 |                      |



Revision: B

# **Signal Description and Assignment**

Figure 2: Device Pinout

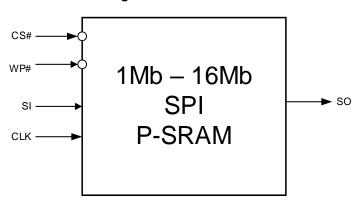


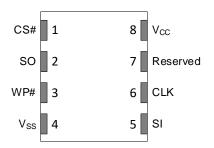
Table 2: Signal Description

| Signal          | Туре   | Description  |
|-----------------|--------|--|
| CS#             | Input  | <b>Chip Select:</b> When CS# is driven High, the device will enter standby mode. All other input pins are ignored and the output pin is tri-stated. Driving CS# Low enables the device, placing it in the active mode. After power-up, a falling edge on CS# is required prior to the start of any instructions.   |
| WP#             | Input  | Write Protect (SPI): Write protects the status register in conjunction with the enable/disable bit of the status register. This is important since other write protection features are controlled through the Status Register. When the enable/disable bit of the status register is set to 1 and the WP# signal is driven Low, the status register becomes read-only and the WRITE STATUS REGISTER operation will not execute. This signal does not have internal pullups, it cannot be left floating and must be driven. |
| CLK             | Input  | <b>Clock:</b> Provides the timing for the serial interface. address and data inputs are latched on the rising edge of the clock. Data is output on the falling edge of the clock.  |
| SI              | Input  | <b>Serial Data Input (SPI):</b> The unidirectional I/O transfers data into the device on the rising edge of the clock in Single SPI mode.  |
| so              | Output | <b>Serial Data Output (SPI):</b> The unidirectional I/O transfers data out of the device on the falling edge of the clock in Single SPI mode.  |
| Vcc             | Supply | V <sub>cc</sub> : Core and I/O power supply.   |
| V <sub>SS</sub> | Supply | V <sub>ss</sub> : Core and I/O ground supply.  |



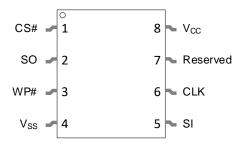
# Package Options 8-Pad WSON (Top View)

Figure 3: 8-Pad WSON



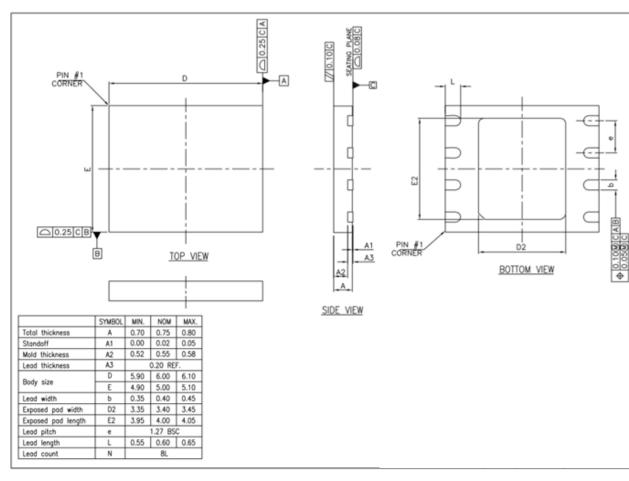
## 8-Pin SOIC (Top View)

Figure 4: 8-Pin SOIC



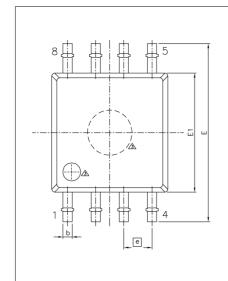


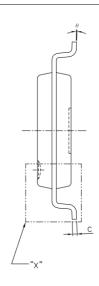
## Package Drawings 8-Pad WSON



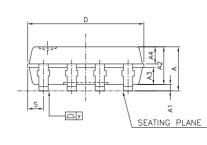
### 1Mbit – 16Mbit SPI P-SRAM Memory

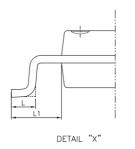
### 8-Pin SOIC





| SYMBOL | DIN   | DIMEN    |       |        |   |
|--------|-------|----------|-------|--------|---|
| 314602 | MIN.  | NOM.     | MAX.  | MIN.   | Г |
| A      |       |          | 2.16  |        | E |
| A1     | 0.05  | 0.15     | 0.25  | 1.97   |   |
| A2     | 1.70  | 1.80     | 1.91  | 66.93  |   |
| A3     | 0.773 | 0.798    | 0.823 | 30.43  |   |
| A4     | 0.773 | 0.798    | 0.823 | 30.43  | Г |
| b      | 0.36  | 0.41     | 0.51  | 14,17  |   |
| С      | 0.19  | 0.20     | 0.25  | 7.48   |   |
| D      | 5.13  | 5.23     | 5.33  | 201.97 | 7 |
| Ε      | 7.70  | 7.90     | 8.10  | 303.15 | 3 |
| E1     | 5.18  | 5.28     | 5.38  | 203.94 | 2 |
| е      |       | 1.27 BSC |       |        | 5 |
| L      | 0.50  | 0.65     | 0.80  | 19.69  |   |
| L1     | 1.27  | 1.37     | 1.47  | 50.00  |   |
| S      | 0.62  | 0.74     | 0.88  | 24.41  |   |
| 9      | 0.    | 5*       | 8*    | 0,     |   |
| у      |       |          | 0.075 |        | - |





#### NOTE:

- DIMENSION "D" DOES NOT INCLUDE MOLD FLASH, PROTE OR GATE BURRS. MOLD FLASH, PROTRUSIONS AND GATE SHALL NOT EXCEED 0,15mm (6mil) PER SIDE.
   DIMENSION "E" DOES NOT INCLUDE INTERLEAD FLASH O PROTRUSIONS. INTER-LEAD FLASH AND PROTRUS SHALL NOT EXCEED 0,25mm (10 mil) PER SIDE.
- 3. CONTROLLING DIMENSION: MILLIMETER



### **Architecture**

ASxxxx401 is a high performance serial STT-MRAM device. It features a SPI-compatible bus interface running at 50MHz, and hardware/software based data protection mechanisms.

When CS# is Low, the device is selected and in active power mode. When CS# is High, the device is deselected but can remain in active power mode until ongoing internal operations are completed. Then the device goes into standby power mode and device current consumption drops to IsB.

ASxxxx401 contains an 8-bit instruction register. All functionality is controlled through the values loaded into this instruction register. The device is accessed via the SPI pins. *Table 3* summarizes all the different interface modes supported and their respective I/O usage. *Table 4* shows the clock edge used for each instruction component.

**Nomenclature adoption**: A typical SPI instruction consists of command, address and data components. The bus width to transmit these three components varies based on the SPI interface mode selected. To accurately represent the number of I/Os used to transmit these three components, a nomenclature (command-address-data) is adopted and used throughout this document. Integers placed in the (command-address-data) fields represent the number of I/Os used to transmit the particular component. 1-1-1 means command, address and data are transmitted on a single I/O.

Table 3: Interface Modes of Operations

| Instruction Component | SPI<br>(1-1-1) |
|-----------------------|----------------|
| Command               | SI             |
| Address               | SI             |
| Data Input            | SI             |
| Data Output           | SO             |

Table 4: Clock Edge Used for instructions

| Instruction Type | Command     | Address    | Data Input | Data Output |
|------------------|-------------|------------|------------|-------------|
| (1-1-1)          | <b>_</b> FR | <b>_</b> R | <b>_</b> R | F₹L         |

#### Notes:

R: Rising Clock Edge F: Falling Clock Edge

ASxxxx401 offers both hardware and software based data protection schemes. Hardware protection is through WP# pin. Software protection is controlled by configuration bits in the Status register. Both schemes inhibit writing to the registers and memory array.

One lower power state is available in ASxxxx401, namely Deep Power Down. Data is not lost while the device is in either of this low power state. Moreover, the device maintains all its configurations.



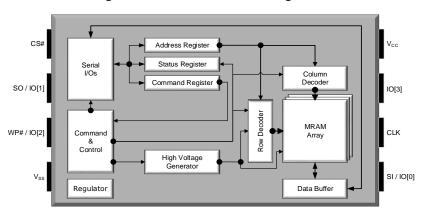


Figure 5: Functional Block Diagram

Table 5: Modes of Operation

| Mode            | Current          | CS#                             | CLK    | SI                           | SO          |
|-----------------|------------------|---------------------------------|--------|------------------------------|-------------|
| Standby         | I <sub>SB</sub>  | H Gated Gated / Hi-Z            |        | Hi-Z / Hi-Z                  |             |
| Active - Read   | IREAD            | L                               | Toggle | Command, Address             | Data Output |
| Active - Write  | IWRITE           | TE L Toggle Command, Address, D |        | Command, Address, Data Input | Hi-Z        |
| Deep Power Down | I <sub>DPD</sub> | Н                               | Gated  | Gated / Hi-Z                 | Hi-Z / Hi-Z |

#### Notes:

H: High (Logic '1') L: Low (Logic '0') Hi-Z: High Impedance



### **Device Initialization**

When powering up, the following procedure is required to initialize the device correctly:

- Ramp up Vcc (RvR)
- CS# must follow V<sub>CC</sub> during power-up (a 10KΩ pull-up Resistor to V<sub>CC</sub> is recommended)
- It is recommended that no instructions are sent to the device when Vcc is below Vcc (minimum)
- During initial Power-up, recovering from power loss or brownout, a delay of tpu is required before normal operation commences
- Upon Power-up, the device is in Standby mode

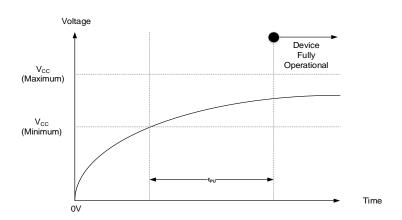


Figure 6: Power-Up Behavior

When powering down, the following procedure is required to turn off the device correctly:

- Ramp down V<sub>CC</sub> (R<sub>VF</sub>)
- CS# must follow V<sub>CC</sub> during power-down (a 10KΩ pull-up Resistor to V<sub>CC</sub> is recommended)
- It is recommended that no instructions are sent to the device when Vcc is below Vcc (minimum)
- The Power-up timing needs to be observed after Vcc goes above Vcc (minimum)

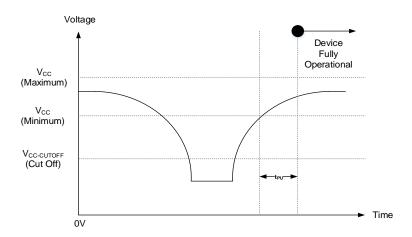


Figure 7: Power-Down Behavior



Table 6: Power Up/Down Timing – 3.0V

| Doromotor                                       | Cumbal                 | Toot Conditions           | 3.0V    |         |         |       |
|---|------------------------|---------------------------|---------|---------|---------|-------|
| Parameter                                       | Symbol Test Conditions |                           | Minimum | Typical | Maximum | Units |
| V <sub>CC</sub> Range                           | Vcc                    |                           | 2.7     | -       | 3.6     | V     |
| V <sub>CC</sub> Ramp Up Time                    | R <sub>VR</sub>        |                           | 30      | -       | -       | μs/V  |
| V <sub>CC</sub> Ramp Down Time                  | Rvf                    |                           | 20      | -       | -       | μs/V  |
| V <sub>CC</sub> Power Up to First Instruction   | <b>t</b> PU            | All operating             | 250     | -       | -       | μs    |
| V <sub>CC</sub> Cutoff – Must Initialize Device | Vcc-<br>cutoff         | voltages and temperatures | 1.6     | -       | -       | V     |
| Time to Enter Deep Power Down                   | t <sub>EDPD</sub>      |                           | -       | -       | 3       | μs    |
| Time to Exit Deep Power Down                    | texdpd                 |                           | -       | -       | 400     | μs    |
| CS# Pulse Width                                 | tcsdpd                 |                           | 50      | -       | -       | ns    |

# **Memory Map**

Table 7: Memory Map

| Density | Address Range     | 24-bit Address [23:0] |                      |  |
|---------|-------------------|-----------------------|----------------------|--|
| 1Mb     | 000000h – 01FFFFh | [23:17] – Logic '0'   | [16:0] - Addressable |  |
| 4Mb     | 000000h – 07FFFFh | [23:19] – Logic '0'   | [18:0] - Addressable |  |
| 8Mb     | 000000h – 0FFFFh  | [23:20] – Logic '0'   | [19:0] - Addressable |  |
| 16Mb    | 000000h – 1FFFFFh | [23:21] – Logic '0'   | [20:0] - Addressable |  |



# **Register Map**

## Status Register / Device Protection Register (Read/Write)

Status register is a legacy SPI register and contains options for enabling/disabling data protection. The register bits are initialized to their default state on device initialization. Any modifications of the bits is volatile, if power is removed then on next boot up the default state is restored.

Table 8: Status Register – Read and Write

| Bits  | Name     | Description   | Read<br>/<br>Write | Default<br>State | Selection<br>Options  |
|-------|----------|---|--------------------|------------------|---|
| SR[7] | WP#EN    | Hardware Based WP#<br>Protection Enable/Disable             | R/W                | 0                | 1: Protection Enabled – write protects when WP# is Low 0: Protection Disabled – Doesn't write protect when WP# is Low |
| SR[6] | Reserved | Reserved  | -                  | -                | -   |
| SR[5] | TBPSEL   | Software Top/Bottom<br>Memory Array Protection<br>Selection | R/W                | 0                | 1: Bottom Protection Enabled (Lower Address Range)     0: Top Protection Enabled (Higher Address Range)               |
| SR[4] | BPSEL[2] | Block Protect Selection Bit 2                               | R/W                | 0                | Block Protection Bits (Table 9,   |
| SR[3] | BPSEL[1] | Block Protect Selection Bit 1                               | R/W                | 0                | ,   |
| SR[2] | BPSEL[0] | Block Protect Selection Bit 0                               | R/W                | 0                | Table <b>10</b> )   |
| SR[1] | WREN     | Write Operation Protection<br>Enable/Disable                | R                  | 0                | Write Operation Protection     Disabled     Write Operation Protection Enabled  |
| SR[0] | RSVD     | Reserved  | R                  | 0                | Reserved for future use   |

Table 9: Top Block Protection Address Range Selection (TBPSEL=0)

| BPSEL<br>[2] | BPSEL<br>[1] | BPSEL<br>[0] | Protected Portion | 1Mb                  | 4Mb                  | 8Mb                  | 16Mb                 |
|--------------|--------------|--------------|-------------------|----------------------|----------------------|----------------------|----------------------|
| 0            | 0            | 0            | None              | None                 | None                 | None                 | None                 |
| 0            | 0            | 1            | Upper 1/64        | 01F800h –<br>01FFFFh | 07E000h –<br>07FFFFh | 0FC000h –<br>0FFFFFh | 1F8000h –<br>1FFFFFh |
| 0            | 1            | 0            | Upper 1/32        | 01F000h –<br>01FFFFh | 07C000h –<br>07FFFFh | 0F8000h –<br>0FFFFFh | 1F0000h –<br>1FFFFFh |
| 0            | 1            | 1            | Upper 1/16        | 01E000h –<br>01FFFFh | 078000h –<br>07FFFFh | 0F0000h –<br>0FFFFFh | 1E0000h –<br>1FFFFFh |
| 1            | 0            | 0            | Upper 1/8         | 01C000h –<br>01FFFFh | 070000h –<br>07FFFFh | 0E0000h –<br>0FFFFFh | 1C0000h –<br>1FFFFFh |
| 1            | 0            | 1            | Upper 1/4         | 018000h –<br>01FFFFh | 060000h –<br>07FFFFh | 0C0000h –<br>0FFFFFh | 180000h –<br>1FFFFFh |
| 1            | 1            | 0            | Upper 1/2         | 010000h –<br>01FFFFh | 040000h –<br>07FFFFh | 080000h –<br>0FFFFFh | 1F0000h –<br>1FFFFFh |
| 1            | 1            | 1            | All               | 000000h –<br>01FFFFh | 000000h –<br>07FFFFh | 000000h –<br>0FFFFFh | 000000h –<br>1FFFFFh |



Table 10: Bottom Block Protection Address Range Selection (TBPSEL=1)

| BPSEL<br>[2] | BPSEL<br>[1] | BPSEL<br>[0] | Protected Portion | 1Mb                  | 4Mb                  | 8Mb                  | 16Mb                 |
|--------------|--------------|--------------|-------------------|----------------------|----------------------|----------------------|----------------------|
| 0            | 0            | 0            | None              | None                 | None                 | None                 | None                 |
| 0            | 0            | 1            | Lower 1/64        | 000000h –<br>0007FFh | 000000h –<br>001FFFh | 000000h –<br>003FFFh | 000000h –<br>007FFFh |
| 0            | 1            | 0            | Lower 1/32        | 000000h –<br>00FFFh  | 000000h –<br>003FFFh | 000000h –<br>007FFFh | 000000h –<br>00FFFFh |
| 0            | 1            | 1            | Lower 1/16        | 000000h –<br>001FFFh | 000000h –<br>007FFFh | 000000h –<br>00FFFFh | 000000h –<br>01FFFFh |
| 1            | 0            | 0            | Lower 1/8         | 000000h –<br>003FFFh | 000000h –<br>00FFFFh | 000000h –<br>01FFFFh | 000000h –<br>03FFFFh |
| 1            | 0            | 1            | Lower 1/4         | 000000h –<br>007FFFh | 000000h –<br>01FFFFh | 000000h –<br>03FFFFh | 000000h –<br>07FFFFh |
| 1            | 1            | 0            | Lower 1/2         | 000000h –<br>00FFFFh | 000000h –<br>03FFFFh | 000000h –<br>07FFFFh | 000000h –<br>0FFFFh  |
| 1            | 1            | 1            | All               | 000000h –<br>01FFFFh | 000000h –<br>07FFFFh | 000000h –<br>0FFFFFh | 000000h –<br>1FFFFFh |

Table 11: Write Protection Modes

| WREN<br>(Status Register) | WP#EN<br>(Status Register) | WP#<br>(Pin) | Status<br>Register | Memory <sup>1</sup><br>Array<br>Protected<br>Area | Memory <sup>1</sup> Array Unprotected Area |
|---------------------------|----------------------------|--------------|--------------------|---|--|
| 0                         | X                          | Х            | Protected          | Protected   | Protected                                  |
| 1                         | 0                          | Х            | Unprotected        | Protected   | Unprotected                                |
| 1                         | 1                          | Low          | Protected          | Protected   | Unprotected                                |
| 1                         | 1                          | High         | Unprotected        | Protected   | Unprotected                                |

#### Notes:

High: Logic '1' Low: Logic '0'

X: Don't Care – Can be Logic '0' or '1'
Protected: Write protected

Unprotected: Writable

1: Memory address range protection based on Block Protection Bits



## Device Identification Register (Read Only)

Device identification register contains Avalanche's Manufacturing ID along with device configuration information.

Table 12: Device Identification Register – Read Only

| Bits      | Avalanche<br>Manufacturer's ID | Device<br>Configuration |           |           |          |         |
|-----------|--------------------------------|-------------------------|-----------|-----------|----------|---------|
| ID[31:0]  | ID[34:34]                      | Interface               | Voltage   | Temp      | Density  | Freq    |
| [ט:ונ]טוו | ID[31:24]                      | ID[23:20]               | ID[19:16] | ID[15:12] | ID[11:8] | ID[7:0] |

| Manufacturer ID | Interface      | Voltage   | Temperature    | Density     | Frequency                            |
|-----------------|----------------|-----------|----------------|-------------|--------------------------------------|
| 31-24           | 23-20          | 19-16     | 15-12          | 11-8        | 7-0                                  |
| 1110 0110       | 0001-SPI (111) | 0001 - 3V | 000040°C- 85°C | 0001 - 1Mb  | 00000110 – 50Mhz                     |
|                 |                |           | 000140°C-105°C | 0010 - 4Mb  | 00000011 – 40Mhz<br>00000100 – 35Mhz |
|                 |                |           |                | 0011 - 8Mb  | 00000100 33MHz                       |
|                 |                |           |                | 0100 - 16Mb |                                      |

Table 13: Memory Read Latency Cycles vs. Maximum Clock Frequency

| Read Type | Latency | Max Frequency ASxxxx2x050xx |
|-----------|---------|-----------------------------|
| 1-1-1     | 0       | 50MHz                       |



## **Instruction Set**

**Table 14: Instruction Set** 

| #  | Instruction<br>Name   | Command<br>(Opcode) | (1-0-0) | (1-0-1) | (1-1-1) | Data Bytes | Max. Frequency         | Prerequisite |
|----|-----------------------|---------------------|---------|---------|---------|------------|------------------------|--------------|
| 1  | No Operation          | NOOP<br>00h         | •       |         |         |            | 50<br>MHz              |              |
| 2  | Write Enable          | WREN<br>06h         | •       |         |         |            | 50MHz                  |              |
| 3  | Write Disable         | WRDI<br>04h         | •       |         |         |            | 50<br>MHz              |              |
| 4  | Enter Deep Power Down | DPDE<br>B9h         | •       |         |         |            | 50<br>MHz              |              |
| 5  | Software Reset Enable | SRTE<br>66h         | •       |         |         |            | 50<br>MHz              |              |
| 6  | Software Reset        | SRST<br>99h         | •       |         |         |            | 50<br>MHz              | SRTE         |
| 7  | Exit Deep Power Down  | DPDX<br>ABh         | •       |         |         |            | 50 <sup>7</sup><br>MHz |              |
| 8  | Read Status Register  | RDSR<br>05h         |         | •       |         | 1          | 50<br>MHz              |              |
| 9  | Read Device ID        | RDID<br>9Fh         |         | •       |         | 4          | 50<br>MHz              |              |
| 10 | Write Status Register | WRSR<br>01h         |         | •       |         | 1          | 50<br>MHz              | WREN         |
| 11 | Read Memory Array     | READ<br>03h         |         |         | •       | 1 to ∞     | 50<br>MHz              |              |
| 12 | Write Memory Array    | WRTE<br>02h         |         |         | •       | 1 to ∞     | 50<br>MHz              | WREN         |

#### Notes:

<sup>1:</sup> A typical SPI instruction consists of command, address and data components. The bus width to transmit these three components varies based on the SPI interface mode selected. To accurately represent the number of I/Os used to transmit these three components, a nomenclature (command-address-data) is adopted and used throughout this document. Integers placed in the (command-address-data) fields represent the number of I/Os used to transmit the particular component. As an example, 1-1-1 means command, address and data are transmitted on a single I/O (SI).

<sup>2:</sup> Registers do not wrap data during reads. Reading beyond the specified number of bytes will yield indeterminate data.



## **Instruction Description and Structures**

All communication between a host and ASxxxx401 is in the form of instructions. Instructions define the operation that must be executed. Instructions consist of a command followed by an optional address modifier and data transfer to or from ASxxxx401. All command, address and data information is transferred sequentially. Instructions are structured as follows:

- Each instruction begins with CS# going Low (logic '0') and ends with CS# returning High (Logic'1').
- CLK marks the transfer of each bit.
- Each instruction starts out with an 8-bit command. The command selects the type of operation ASxxxx401 must perform. The command is transferred on the rising edges of CLK.
- The command can be stand alone or followed by address to select a memory location or register. The address is always 24-bits wide.
  - The address is transferred on the rising edges of CLK.
- The address bits are followed by data bits. For Write instructions:
  - Write data bits to ASxxxx401 are transferred on the rising edges of CLK.
- Write instructions must be preceded by the WREN instruction. WREN instruction sets the WREN bit in the Status register. WREN bit is reset at the end of every Write instruction. WREN bit can also be reset by executing the WRDI instruction.
- Similar to write instructions, In read instructions, the address bits are followed by data bits for read instructions:
  - Read data bits from ASxxxx401 are transferred on the falling edges of CLK.
- The entire memory array can be read from or written to using a single read or write instruction. After the staring address is entered, subsequent address are internally incremented as long as CS# is Low and CLK continues to cycle.
- All commands, address and data are shifted with the most significant bit first.

Figure 8 to Figure 10 show the description of instruction types supported.

Figure 8: Description of (1-0-0) Instruction Type

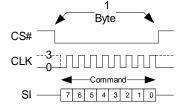




Figure 9: Description of (1-0-1) Instruction Type

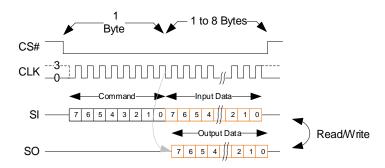
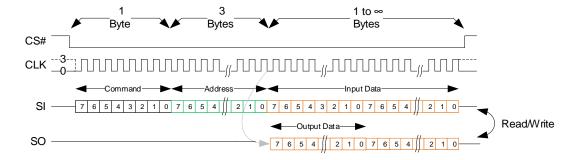


Figure 10: Description of (1-1-1) Instruction Type





# **Electrical Specifications**

**Table 15: Recommended Operating Conditions** 

| The second secon |                 |         |         |       |    |  |  |  |
|--|-----------------|---------|---------|-------|----|--|--|--|
| Parameter / Co   | Minimum         | Typical | Maximum | Units |    |  |  |  |
| Operating Temperature  | Industrial      | -40.0   | -       | 85.0  | °C |  |  |  |
| Operating Temperature  | Industrial Plus | -40.0   | -       | 105.0 | °C |  |  |  |
| V <sub>CC</sub> Supply Voltage (3.0V)  | 3.0V            | 2.7     | 3.0     | 3.6   | V  |  |  |  |
| V <sub>SS</sub> Supply Voltage   |                 | 0.0     | 0.0     | 0.0   | V  |  |  |  |

### Table 16: Pin Capacitance

| Parameter              | Test Conditions                                   | Symbol | Maximum | Units |
|------------------------|---|--------|---------|-------|
| Input Pin Capacitance  | TEMP = 25°C; f = 1 MHz; V <sub>IN</sub> = 3.0V    | Cin    | 5.0     | pF    |
| Output Pin Capacitance | TEMP = $25^{\circ}$ C; f = 1 MHz; $V_{IN} = 3.0V$ | CINOUT | 6.0     | pF    |

### Table 17: Endurance & Retention

| Parameter       | Symbol | Test Conditions | Minimum          | Units  |
|-----------------|--------|-----------------|------------------|--------|
| Write Endurance | END    | -               | 10 <sup>14</sup> | cycles |
|                 |        | 105°C           | 10               |        |
| Data Batantian  | DET    | 85°C 1,000      |                  |        |
| Data Retention  | RET    | 75°C            | 10,000           | years  |
|                 |        | 65°C            | 1,000,000        |        |



## 1Mbit – 16Mbit SPI P-SRAM Memory

### Table 18: 3.0V DC Characteristics

|                           |                  |  |              | 3.0V E  | Device (2.7 | V-3.6V) |       |
|---------------------------|------------------|--|--------------|---------|-------------|---------|-------|
| Parameter                 | Symbol           | Test Conditions  | <b>S</b>     | Minimum | Typical     | Maximum | Units |
| Read Current (1-1-1)      | IREAD1           | Vcc = 3.6V, Iout=0mA,<br>CLK=50MHz (V <sub>IL</sub> / V <sub>IH</sub> ),<br>CS#= V <sub>IL</sub> , SI= V <sub>IL</sub> or V <sub>IH</sub>              |              | -       | 8           | 9       | mA    |
| Write Current (1-1-1)     | Iwrite1          | Vcc = 3.6V, I <sub>OUT</sub> =0mA,<br>CLK=50MHz (V <sub>IL</sub> / V <sub>IH</sub> ),<br>CS#= V <sub>IL</sub> , SI= V <sub>IL</sub> or V <sub>IH</sub> |              | -       | 14          | 16      | mA    |
|                           |                  |  | Ta = 25°C    | -       | 160         | -       | μA    |
| Standby Current           | I <sub>SB</sub>  | V <sub>CC</sub> = 3.6V, CLK=V <sub>CC</sub> ,<br>CS#=V <sub>CC</sub> , SI=V <sub>CC</sub>  | Ta = 85°C    | -       | -           | 500     | μA    |
|                           |                  | 00#= vcc, 01= vcc  | Ta =105°C    | -       | -           | 700     | μA    |
| Deep Power Down Current   | I <sub>DPD</sub> | Vcc = 3.6V, CLK=Vcc, CS#=  | ·Vcc, SI=Vcc | -       | 5           | 25      | μA    |
| Input Leakage Current     | ILI              | V <sub>IN</sub> =0 to V <sub>CC</sub> (max   | <b>(</b> )   | -       | -           | ±1.0    | μA    |
| Output Leakage Current    | ILO              | Vout=0 to Vcc (ma  | ax)          | -       | -           | ±1.0    | μA    |
| Input High Voltage        | ViH              |  |              | 0.7xVcc | -           | Vcc+0.3 | V     |
| Input Low Voltage         | VIL              |  |              | -0.3    | -           | 0.3xVcc | V     |
| Output High Voltage Lavel | \ \ \\           | I <sub>OH</sub> = -100μA   |              | Vcc-0.2 | -           | -       | V     |
| Output High Voltage Level | Vон              | I <sub>OH</sub> = -1mA   |              | 2.4     | -           | -       | V     |
| Output Law Valtage Laws   | V                | I <sub>OL</sub> = 150μA  |              | -       | -           | 0.2     | V     |
| Output Low Voltage Level  | VoL              | I <sub>OL</sub> = 2mA  |              | -       | -           | 0.4     | V     |



## **Absolute Maximum Ratings**

Stresses greater that those listed may cause permanent damage to the device. This is a stress rating only. Exposure to maximum rating for extended periods may adversely affect reliability.

Table 19: Absolute Maximum Ratings

| Parameter   | Minimum | Maximum | Units |
|---|---------|---------|-------|
| Magnetic Field During Write                                   |         | 24000   | A/m   |
| Magnetic Field During Read                                    |         | 24000   | A/m   |
| Junction Temperature  |         | 125     | °C    |
| Storage Temperature   | -55 to  | 150     | °C    |
| ESD HBM (Human Body Model)<br>ANSI/ESDA/JEDEC JS-001-2017     | ≥  200  | 00 V    | V     |
| ESD CDM (Charged Device Model)<br>ANSI/ESDA/JEDEC JS-002-2018 | ≥  50   | 0 V     | V     |
| Latch-Up (I-test)<br>JESD78                                   | ≥  100  | mA      | mA    |
| Latch-Up (Vsupply over-voltage test) JESD78                   | Pass    | sed     |       |

Table 20: AC Test Conditions

| Parameter                                  | Value              |
|--|--------------------|
| Input pulse levels                         | 0.0V to Vcc        |
| Input rise and fall times                  | 3.0ns              |
| Input and output measurement timing levels | V <sub>cc</sub> /2 |
| Output Load                                | CL = 30.0pF        |



# **CS# Operation & Timing**

CS# **CLK** 

Figure 11: CS# Operation & Timing

Table 21: CS# Operation

| Parameter  | Symbol           | Minimum        | Maximum | Units |
|--|------------------|----------------|---------|-------|
| Clock Frequency  | fclk             | 1              | 50      | MHz   |
| Clock Low Time   | tcL              | 0.45 * 1/ fclk | -       | ns    |
| Clock High Time  | tсн              | 0.45 * 1/ fclk | -       | ns    |
| Chip Deselect Time after Read Cycle                        | tcs1             | 20             | -       | ns    |
| Chip Deselect Time after Register Write Cycle <sup>1</sup> | t <sub>CS2</sub> | 5              | -       | μs    |
| Chip Deselect Time after Write Cycle                       | tcs3             | 280            | -       | ns    |
| CS# Setup Time (w.r.t CLK)                                 | tcss             | 5              | -       | ns    |
| CS# Hold Time (w.r.t CLK)                                  | tсsн             | 4              | -       | ns    |

Notes:



# Command, Address and Data Input Operation & Timing

Figure 12: Command, Address and Data Input Operation & Timing

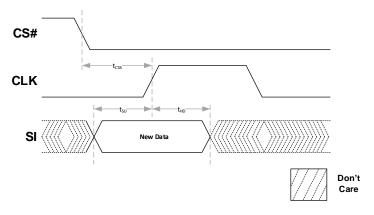


Table 22: Command, Address and Data Input Operation & Timing

| Parameter                   | Symbol          | Minimum | Maximum | Units |
|-----------------------------|-----------------|---------|---------|-------|
| Data Setup Time (w.r.t CLK) | t <sub>SU</sub> | 2.0     | -       | ns    |
| Data Hold Time (w.r.t CLK)  | t <sub>HD</sub> | 3.0     | -       | ns    |

#### Notes:



## **Data Output Operation & Timing**

Figure 13: Data Output Operation & Timing

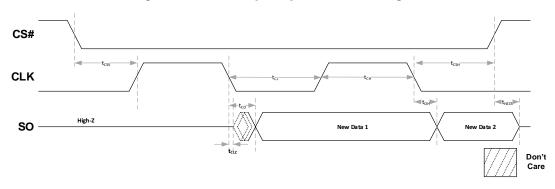


Table 23: Data Output Operation & Timing

| Parameter                        | Symbol | Minimum | Maximum | Units |
|----------------------------------|--------|---------|---------|-------|
| CLK Low to Output Low Z (Active) | tcLz   | 0       | -       | ns    |
| Output Valid (w.r.t CLK)         | tco    | -       | 7.0     | ns    |
| Output Hold Time (w.r.t CLK)     | tон    | 1.0     | -       | ns    |
| Output Disable Time (w.r.t CS#)  | thzcs  | -       | 7.0     | ns    |

Notes:



## **WP# Operation & Timing**

Figure 14: WP# Operation & Timing

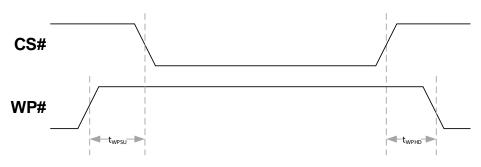


Table 24: WP# Operation & Timing

| Parameter                  | Symbol | Minimum | Maximum | Units |
|----------------------------|--------|---------|---------|-------|
| WP# Setup Time (w.r.t CS#) | twpsu  | 20      | -       | ns    |
| WP# Hold Time (w.r.t CS#)  | twphd  | 20      | -       | ns    |

Notes:



### **JEDEC Reset Operation & Timing**

Figure 15: JEDEC Reset Operation & Timing

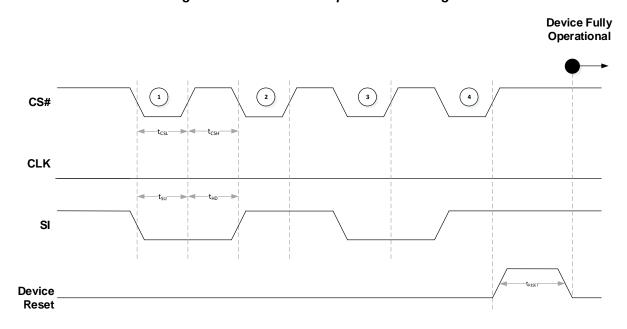


Table 25: JEDEC Reset and Software Reset Timing

| Parameter                   | Symbol | Minimum | Maximum | Units |
|-----------------------------|--------|---------|---------|-------|
| CS# Low Time                | tcL    | 1.0     | -       | μs    |
| CS# High Time               | tсн    | 1.0     | -       | μs    |
| SI Setup Time (w.r.t CS#)   | tsu    | 5.0     | -       | ns    |
| SI Hold Time (w.r.t CS#)    | tho    | 5.0     | -       | ns    |
| JEDEC Hardware Reset        | treset | -       | 450.0   | μs    |
| Software Reset <sup>1</sup> | tsrst  | -       | 50.0    | us    |

### Notes:

<sup>1:</sup> Software Reset timing is for Instruction based Reset (SRST)



### **Enter Deep Power Down Command (DPDE – B9h)**

The command sequences are shown below. Executing the Enter Deep Power down (DPDE) command is the only way to put the device in the deep power down mode. The device consumption drops to I<sub>DP</sub>.

The deep power down mode subsequently reduces the standby current from I<sub>SB</sub> to I<sub>DP</sub>. No other command must be issued while the device is in deep power down mode.

To enter the deep power down mode, CS# is driven low, following the enter deep power down (DPDE) command, CS# must be driven high after the eighth bit of the command code has been latched in or the DPDE command will not be executed. After CS# is driven high, it requires a delay of tedped (Table 6 and 7) before the supply current is reduced to IDP and the Deep Power Down mode is entered.

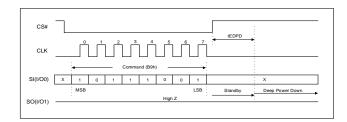


Figure 16: Enter Deep Power Down in SPI Command Sequence



### **Exit Deep Power Down Command (DPDX - ABh)**

The command sequences are shown below. There are two ways to exit deep power down mode:

- 1. Toggling CS# with a CS# pulse width of tCSDPD while CLK and I/Os are Don't Care. During waking up from deep power down, I/Os remain to be in high Z.
- 2. Driving CS# low follows with the Exit Deep Power Down (DPDX) command. CS# must be driven high after the eight bit of the command code has been latched in or the DPDX command will not executed.

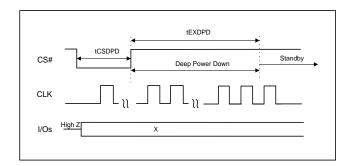


Figure 17: Exit Deep Power Down by Toggling CS#

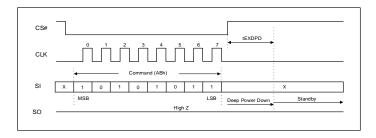


Figure 18: Exit Deep Power Down in SPI Command Sequence

It requires a delay of  $t_{\text{EXDPD}}$  (Table 6 and 7) before the device can fully exit the deep power down mode and enter standby mode. Status of all volatile bits in registers remains unchanged when the device enters or exits the deep power down mode.



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# **Revision History**

| Revision | Date       | Change Summary  |  |
|----------|------------|---|--|
| REV A    | 09/14/2020 | Initial release.  |  |
| REV B    | 06/22/2021 | Added REACH Compliance to RoHS Compliance. Updated Device ID table to have 40, 35 & 27MHz options Updated Product Use Limitations |  |

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MR4A08BCYS35 MR4A16BCYS35 MR0D08BMA45R MR4A08BMA35 MR4A08BCMA35 AS1016204-0108X0PWAY AS30042040054X0IWAY AS3001204-0054X0IWAY AS3004204-0054X0PWAY MR10Q010SC M3032316045NX0IBCY AS1016204-0108X0PSAY

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MR25H256AMDF MR25H128AMDF MR25H128ACDF MR0A08BMA35 MR0DL08BMA45 MR10Q010VSC MR1A16AMA35

MR256A08BCMA35 MR256A08BMA35 MR25H10MDF MR25H256MDF MR25H40VDF MR2A08ACMA35 MR2A08AMA35

MR2A16AMA35 MR5A16AYS35 MR5A16ACYS35 MR3A16AYS35 MR4A08BUYS45 MR4A08BYS35 MR4A16BCMA35